Bulletin PD-2.304 rev. F 11/04

International
IOR Rectifier

31DQ03
31DQ04

SCHOTTKY RECTIFIER 3.3 Amp

Major Ratings and Characteristics

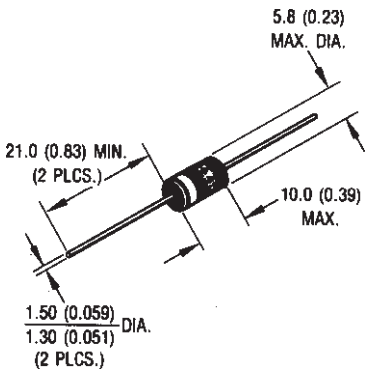
Characteristics	Values	Units
$I_{F(AV)}$ Rectangular waveform	3.3	A
V_{RRM}	30/40	V
I_{FSM} @tp = 5 µs sine	450	A
V_F @3 Apk, T_J = 25°C	0.57	V
T_J	-40 to 150	°C

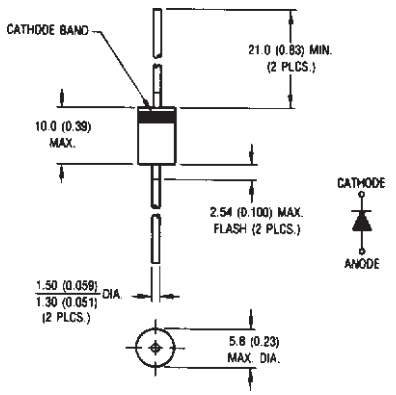
Description/Features

The 31DQ.. axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- Low profile, axial leaded outline
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead-Free plating

CASE STYLE AND DIMENSIONS





Outline C - 16
Dimensions in millimeters and inches

Voltage Ratings

Part number		31DQ03	31DQ04
V_R	Max. DC Reverse Voltage (V)	30	40
V_{RWM}	Max. Working Peak Reverse Voltage (V)		

Absolute Maximum Ratings

Parameters		31DQ..	Units	Conditions	
$I_{F(AV)}$	Max. Average Forward Current * See Fig. 4	3.3	A	50% duty cycle @ T_C = 73°C, rectangular wave form	
I_{FSM}	Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 6	450	A	5µs Sine or 3µs Rect. pulse	Following any rated load condition and with rated V_{RRM} applied
		90		10ms Sine or 6ms Rect. pulse	
E_{AS}	Non-Repetitive Avalanche Energy	6.0	mJ	T_J = 25 °C, I_{AS} = 1.0 Amps, L = 12 mH	
I_{AR}	Repetitive Avalanche Current	1.0	A	Current decaying linearly to zero in 1 µsec Frequency limited by T_J max. V_A = 1.5 x V_R typical	

Electrical Specifications

Parameters		31DQ..	Units	Conditions	
V_{FM}	Max. Forward Voltage Drop * See Fig. 1 (1)	0.57	V	@ 3A	T_J = 25 °C
		0.71	V	@ 6A	
		0.51	V	@ 3A	T_J = 125 °C
		0.62	V	@ 6A	
I_{RM}	Max. Reverse Leakage Current * See Fig. 2 (1)	1	mA	T_J = 25 °C	V_R = rated V_R
		20	mA	T_J = 125 °C	
C_T	Typical Junction Capacitance	190	pF	V_R = 5V_{DC} (test signal range 100Khz to 1Mhz) 25°C	
L_S	Typical Series Inductance	9.0	nH	Measured lead to lead 5mm from package body	
dv/dt	Max. Voltage Rate of Change	10000	V/µs	(Rated V_R)	

(1) Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications

Parameters		31DQ..	Units	Conditions
T_J	Max. Junction Temperature Range (*)	-40 to 150	°C	
T_{stg}	Max. Storage Temperature Range	-40 to 150	°C	
R_{thJA}	Max. Thermal Resistance Junction to Ambient	80	°C/W	DC operation Without cooling fins
R_{thJL}	Typical Thermal Resistance Junction to Lead	34	°C/W	With fin 20 x 20 (0.79 x 0.79) 1.0 (0.04) thick. Dimensions in millimeters (inches)
wt	Approximate Weight	1.2 (0.042)	g (oz.)	
	Case Style	C - 16		

(*) $\frac{dPtot}{dTj} < \frac{1}{Rth(j\text{-}a)}$ thermal runaway condition for a diode on its own heatsink

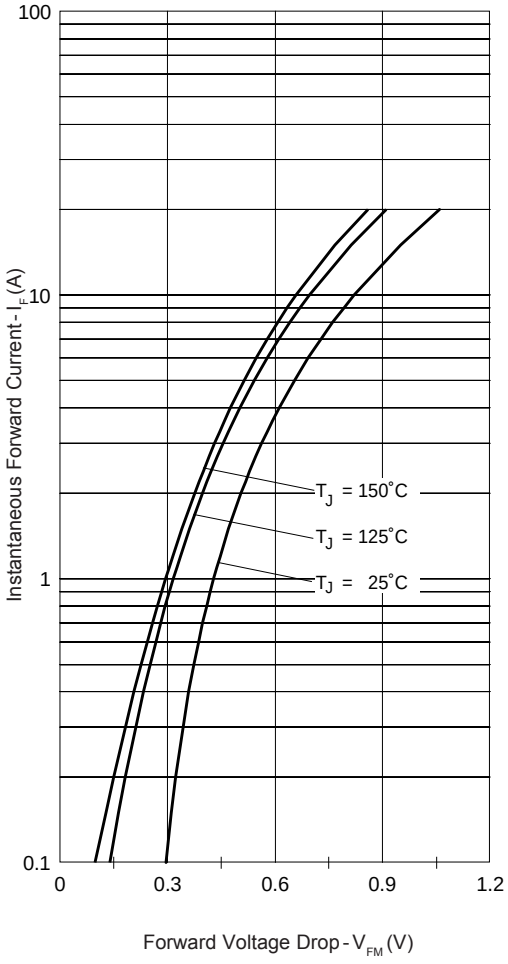


Fig. 1 - Max. Forward Voltage Drop Characteristics

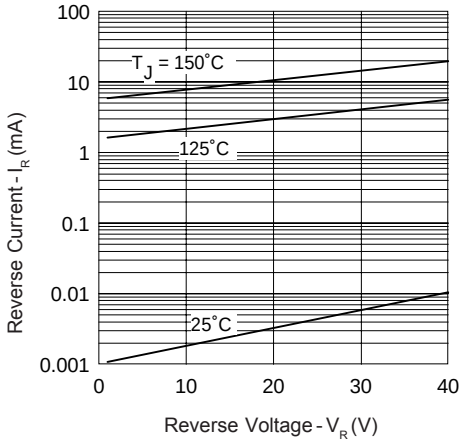


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

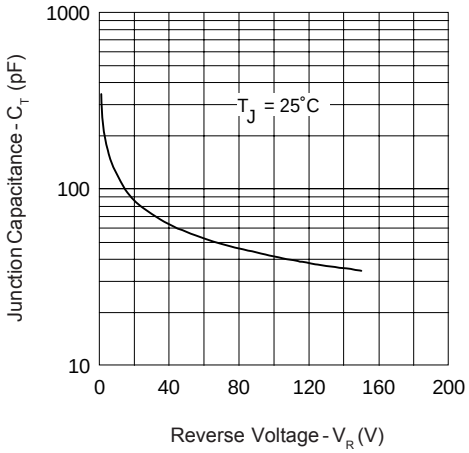


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

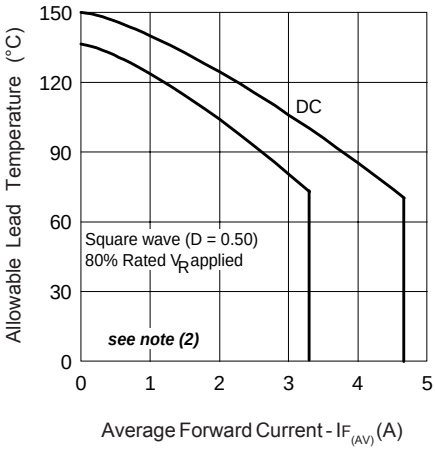


Fig. 4 - Max. Allowable Lead Temperature Vs. Average Forward Current

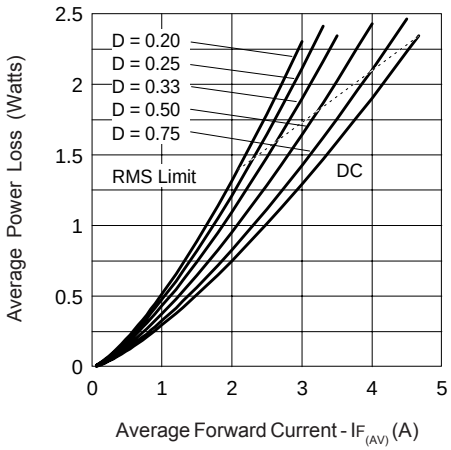


Fig. 5 - Forward Power Loss Characteristics

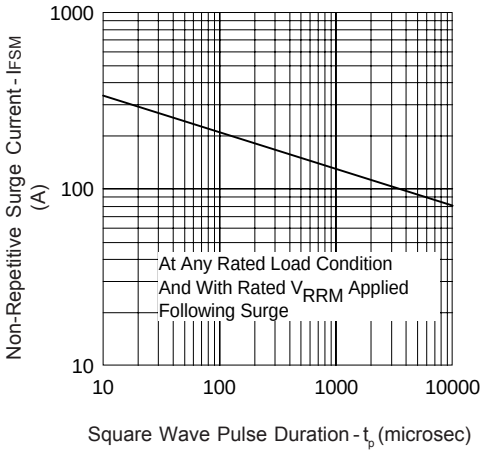
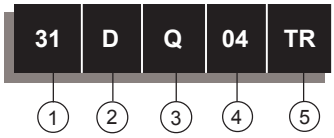


Fig. 6 - Max. Non-Repetitive Surge Current

(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
Pd = Forward Power Loss = $I_{F(AV)} \times V_{FM}$ @ ($I_{F(AV)}$ / D) (see Fig. 6);
Pd_{REV} = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; I_R @ V_{R1} = 80% rated V_R

Ordering Information Table

Device Code



1	-	31 =	3.1A (Axial and small packages - Current is x10)
2	-	D =	DO-201 package
3	-	Q =	Schottky Q.. Series
4	-	04 =	Voltage Ratings (04 = 40V, 03 = 30V)
5	-	TR =	Tape & Reel package (1200 pcs)
	-	=	Box package (500 pcs)

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level and Lead-Free.
Qualification Standards can be found on IR's Web site.

International
IOR Rectifier

IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105
TAC Fax: (310) 252-7309
11/04

Notice

The products described herein were acquired by Vishay Intertechnology, Inc., as part of its acquisition of International Rectifier's Power Control Systems (PCS) business, which closed in April 2007. Specifications of the products displayed herein are pending review by Vishay and are subject to the terms and conditions shown below.

Specifications of the products displayed herein are subject to change without notice. Vishay Intertechnology, Inc., or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Vishay's terms and conditions of sale for such products, Vishay assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of Vishay products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Vishay for any damages resulting from such improper use or sale.

International Rectifier®, IR®, the IR logo, HEXFET®, HEXSense®, HEXDIP®, DOL®, INTERO®, and POWIRTRAIN® are registered trademarks of International Rectifier Corporation in the U.S. and other countries. All other product names noted herein may be trademarks of their respective owners.